	Туре	Hits	Search Text	DBs	Time Stamp	Cime
	BRS	68029	(a-si or asi or ((amorphous or alpha) near2 (si or silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17	11:39
	BRS	2136	asi or ar2 (si D or "ph n" or sp	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17	10:58
	BRS	74999	(aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17	10:58
	BRS	11723 5	polysilicon or poly-silicon or polysi or poly-si or (poly near2 (si or silicon))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 10:58	10:58
	BRS	11790 75	crystal\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17	10:59
	BRS	474	((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6) near8 (polysilicon or poly-silicon or polysi or poly-si or (poly near2 (si or silicon))) near8 crystal\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 10:59	10:59
	BRS	360	((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6) near8 crystal\$6) near8 crystal\$6 or poly-silicon or polysi or poly-si or (poly near2 (si or silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 10:59	10:59

	Type	Hits	Search Text	DBs	Time Stamp
	BRS	35	(((a-si or asi or ((amorphous or alpha) near2 (si or silicon))) near8 (PVD or "physical vapor deposition" or sputter\$6)) and (((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6) near8 crystal\$6 near8 (polysilicon or poly-silicon or polysilicon or poly-si or poly-si or poly-si or silicon))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 10:59
	BRS	59622	(TFT or "thin film transistor" or T-F-T)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:00
10	BRS	16177	(metal adj induc\$4 adj crystal\$6) or MIC	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:00
11	BRS	861	((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6) same crystal\$6 same (polysilicon or poly-silicon or polysi or poly-si or (poly near2 (si or silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
12	BRS	6	(((a-si or asi or ((amorphous or alpha) near2 (si or silicon))) near8 (PVD or "physical vapor deposition" or sputter\$6)) and (((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6) same crystal\$6 same (polysilicon or poly-silicon or polysior poly-si	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01

	Туре	Hits	Search Text	DBs	Time Stamp
13	BRS	2 8	or asi ar2 (s D or " um or um or nicke or pal or Ge stal\$6 ilicon r (pol)) a	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
14	BRS	8	((((a-si or asi or (amorphous or alpha) near2 (si or silicon))) near8 (PVD or "physical vapor deposition" or sputter\$6)) and (((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6) near8 crystal\$6 near8 (polysilicon or poly-silicon or polysilicon or poly-si or (poly near2 (si or silicon)))) and ((TFT or "thin film transistor" or T-F-T))) and ((metal adj induc\$4 adj crystal\$6) or MIC)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
15	IS&R	814	(438/166).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
16	IS&R	745	(438/482).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:31
17	BRS	7054	SPC or (suppress\$6 near2 (partial adj solid adj phase adj crystalliz\$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:39

	Туре	Hits	Search Text	DBs	Time Stamp
18	BRS	208	(SPC or (suppress\$6 near2 (partial adj solid adj phase adj crystalliz\$6))) same ((a-si or asi or (amorphous or alpha) near2 (si or silicon))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:39
19	BRS	80	((SPC or (suppress\$6 near2 (partial adj solid adj phase adj crystalliz\$6))) same ((a-si or asi or (amorphous or alpha) near2 (si or silicon))))) and (@ad<20001025)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:44
20	BRS	34	(((SPC or (suppress\$6 near2 (partial adj solid adj phase adj crystalliz\$6)) same ((a-si or asi or ((amorphous or alpha) near2 (si or silicon)))) and (@ad<20001025)) and ((aluminum or ITO or "indium tin oxide" or nickel or ni or cobalt or co or Al or palladium or pd or germanium or Ge) near8 crystal\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:44

	Type	#	Hits	Search Text	DBs Time	Time Stamp
1	IS&R	13	463	1 1 1 1 1 1 1 1 1	USPAT; US-PGP UB; EPO; JPO; JERWEN 14:32 T; IBM_TD	09/17
7	IS&R	Г.3	120	1 1 1 1 1 1 1 1 1 1	USPAT; US-PGP UB; EPO; JPO; DERWEN 14:59 T; IBM_TD	09/17